

# 3.3 VOLT TIME SLOT INTERCHANGE DIGITAL SWITCH 1,024 x 1,024

IDT72V70210

## **FEATURES:**

- 32 serial input and output streams
- 1,024 x 1,024 channel non-blocking switching at 2.048 Mb/s
- Per-channel Variable Delay Mode for low-latency applications
- Per-channel Constant Delay Mode for frame integrity applications
- Automatic identification of ST-BUS® and GCI serial streams
- · Automatic frame offset delay measurement
- Per-stream frame delay offset programming
- · Per-channel high impedance output control
- Per-channel processor mode to allow microprocessor writes to TX streams
- Direct microprocessor access to all internal memories
- Memory block programming for quick set-up
- IEEE-1149.1 (JTAG) Test Port
- · Internal Loopback for testing
- Available in 144-pin Ball Grid Array (BGA) and 144-pin Thin Quad

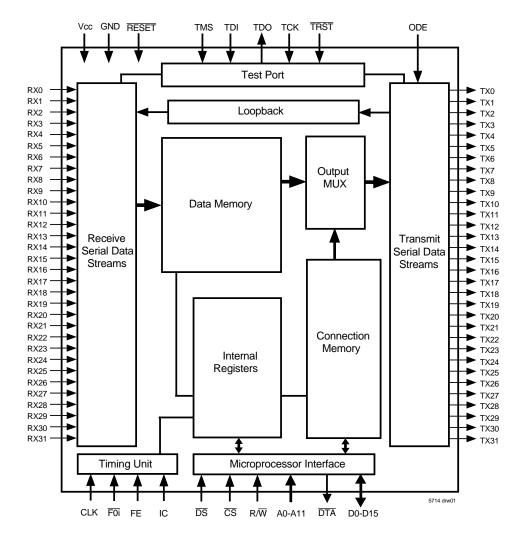
- Flatpack (TQFP) packages
- Operating Temperature Range -40°C to +85°C
- 3.3V I/O with 5V tolerant inputs and TTL compatible outputs

## **DESCRIPTION:**

The IDT72V70210 has a non-blocking switch capacity of 1,024 x 1,024 channels at 2.048 Mb/s. With 32 inputs and 32 outputs, programmable per stream control, and a variety of operating modes the IDT72V70210 is designed for the TDM time slot interchange function in either voice or data applications.

Some of the main features of the IDT72V70210 are low power 3.3 Volt operation, automatic ST-BUS\*/GCI sensing, memory block programming, simple microprocessor interface, one cycle direct internal memory accesses, JTAG Test Access Port (TAP) and per stream programmable input offset delay, variable or constant throughput modes, internal loopback, output enable, and Processor Mode.

## **FUNCTIONAL BLOCK DIAGRAM**



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**JANUARY 2002** 

## **PIN CONFIGURATIONS**

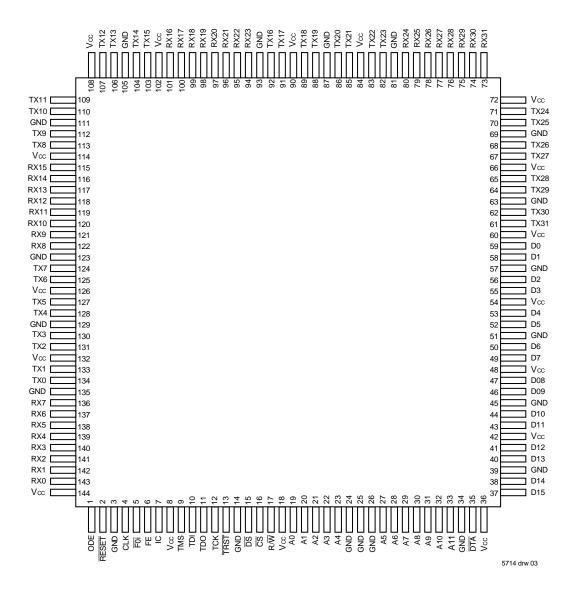
	×	A	1 BALL PA	AD CORI	NER							
A	O RX0	O RX1	O RX3	O RX6	O TX1	O TX4	O TX7	O RX10	O RX12	O RX15	O TX10	O TX11
В	O CLK	O ODE	O RX2	O RX5	O TX0	O TX3	O TX6	O RX9	O RX13	O RX14	O TX9	O TX12
С	O F0i	O FE	O RESET	O RX4	O RX7	O TX2	O TX5	O RX8	O RX11	O TX8	O TX13	O TX14
D	O TMS	O	O TDI	O GND	O	O	O	O	O	O TX15	O RX16	O RX17
E	O TD0	O TCK	O TRST	O vcc	O GND	O GND	O GND	O GND	O vcc	O RX19	O RX20	O RX21
F	O DS	O CS	O R/W	VCC	O GND	O GND	O GND	O GND	O	O RX22	O RX23	O RX18
G	O A0	O A1	O A2	O	O GND	O GND	O GND	O GND	O	O TX16	O TX17	O TX18
н	O A3	O A4	O A5	O	O GND	O GND	O GND	O GND	O vcc	O TX19	O TX20	O TX21
J	O A6	O A7	O A8	O D15	O vcc	O	O vcc	O	O GND	O TX22	O RX24	O TX23
K	O A9	O A10	O DTA	O D9	O D6	O D3	O D0	O TX29	O TX26	O RX27	O RX25	O RX26
L	O A11	O	O D12	O D11	O D7	O D4	O D1	O TX30	O TX27	O TX24	O RX28	O RX29
M	OIC	O D14	O D13	O D10	O D8	O D5	O D2	O TX31	O TX28	O TX25	O RX31	O RX30
	1	2	3	4	5	6	7	8	9	10	11	<b>12</b> 5714 drw 02

## NOTES:

- 1. IC Internal Connection, tie to Ground for normal operation. 2. All I/O pins are 5V tolerant except for TMS, TDI and  $\overline{\text{TRST}}$ .

BGA: 1mm pitch, 13mm x 13mm (BC144-1, order code: BC) TOP VIEW

## **PIN CONFIGURATIONS (CONTINUED)**



## NOTES:

- 1. IC Internal Connection, tie to Ground for normal operation.
- 2. All I/O pins are 5V tolerant except for TMS, TDI and  $\overline{\text{TRST}}$ .

TQFP: 0.50mm pitch, 20mm x 20mm (DA144-1, order code: DA)
TOP VIEW

## **PIN DESCRIPTION**

SYMBOL	NAME	I/O	DESCRIPTION
GND	Ground.		Ground Rail.
Vcc	Vcc		+3.3 Volt Power Supply.
TX0-31	TX Output 0 to 31 (Three-state Outputs)	0	Serial data output stream. These streams have a data rate of 2.048 Mb/s.
RX0-31	RX Input 0 to 31	1	Serial data input stream. These streams have a data rate of 2.048 Mb/s.
F0i	Frame Pulse	I	This input accepts and automatically identifies frame synchronization signals formatted according to ST-BUS® and GCI specifications.
FE	Frame Evaluation	1	This pin is the frame measurement input.
CLK	Clock	1	Serial clock for shifting data in/out on the serial streams (RX/TX 0-31). This input accepts a 4.096 MHz clock.
TMS	Test Mode Select	I	JTAG signal that controls the state transitions of the TAP controller. This pin is pulled HIGH by an internal pull-up when not driven.
TDI	Test Serial Data In	I	JTAG serial test instructions and data are shifted in on this pin. This pin is pulled HIGH by an internal pull-up when not driven.
TDO	Test Serial Data Out	0	JTAG serial data is output on this pin on the falling edge of TCK. This pin is held in high-impedance state when JTAG scan is not enabled.
TCK	Test Clock	I	Provides the clock to the JTAG test logic.
TRST	Test Reset	I	Asynchronously initializes the JTAG TAP controller by putting it in the Test-Logic-reset state. This pin is pulled by an internal pull-up when not driven. This pin should be pulsed LOW on power-up, or held LOW, to ensure that the IDT72V70210 is in the normal functional mode.
RESET	Device Reset (Schmitt Trigger Input)	I	This input (active LOW) puts the IDT72V70210 in its reset state that clears the device internal counters, registers and brings TX0-31 and microport data outputs to a high-impedance state. The time constant for a power up reset circuit must be a minimum of five times the rise time of the power supply. In normal operation, the RESET pin must be held LOW for a minimum of 100ns to reset the device.
DS	Data Strobe	1	This active LOW input works in conjunction with $\overline{CS}$ to enable the read and write operations.
R/W	Read/Write	I	This input controls the direction of the data bus lines during a microprocessor access.
CS	Chip Select	1	Active LOW input used by a microprocessor to activate the microprocessor port of IDT72V70210.
A0-11	Address Bus 0 to 11	I	These pins allow direct access to Connection Memory, Data Memory and internal control registers.
D0-15	Data Bus 0-15	I/O	These pins are the data bits of the microprocessor port.
DTA	Data Transfer Acknowledgment	0	This active LOW signal indicates that a data bus transfer is complete. When the bus cycle ends, this pin drives HIGH and then goes high-impedance, allowing for faster bus cycles with a weaker pull-up resistor. A pull-up resistor is required to hold a HIGH level when the pin is in high-impedance.
ODE	Output Drive Enable	I	This is the output enable control for the TX0-31 serial outputs. When ODE input is LOW and the OSB bit of the CR register is LOW, TX0-31 are in a high-impedance state. If this input is HIGH, the TX0-31 output drivers are enabled. However, each channel may still be put into a high-impedance state by using the per channel control bit in the connection memory.

## **DESCRIPTION (CONTINUED):**

The IDT72V70210 is capable of switching up to  $1,024 \times 1,024$  channels without blocking. Designed to switch  $64 \times 10^{-2}$  Kbit/s PCM or N  $\times 64 \times 10^{-2}$  Kbit/s data, the device maintains frame integrity in data applications and minimizes throughput delay for voice applications on a per channel basis.

The 32 serial input streams (RX) of the IDT72V70210 can be run 2.048 Mb/s allowing 32 channels per  $125\mu s$  frame. The data rates on the output streams (TX) are identical to those on the input stream.

With two main operating modes, Processor Mode and Connection Mode, the IDT72V70210 can easily switch data from incoming serial streams (Data Memory) or from the controlling microprocessor (Connection Memory). As control and status information is critical in data transmission, the Processor Mode is especially useful when there are multiple devices sharing the input and output streams.

With data coming from multiple sources and through different paths, data entering the device is often delayed. To handle this problem, the IDT72V70210 has a frame evaluation feature to allow individual streams to be offset from the frame pulse in half clock-cycle intervals up to +4.5 clock cycles.

The IDT72V70210 also provides a JTAG test access port, an internal loopback feature, memory block programming, a simple microprocessor interface and automatic ST-BUS $^{\circ}$ /GCI sensing to shorten setup time, aid in debugging and ease use of the device without sacrificing capabilities.

## **FUNCTIONAL DESCRIPTION**

#### **DATA AND CONNECTION MEMORY**

All data that comes in through the RX inputs go through a serial-to-parallel conversion before being stored into internal Data Memory. The 8 KHz frame pulse ( $\overline{\text{F0i}}$ ) is used to mark the 125µs frame boundaries and to sequentially address the input channels in Data Memory.

Data output on the TX streams may come from either the Serial Input Streams, RX0-31, (Data Memory) or from the microprocessor (Connection Memory). In the case that RX input data is to be output, the addresses in connection memory are used to specify a stream and channel of the input. The connection memory is setup in such a way that each location corresponds to an output channel for each particular stream. In that way, more than one channel can output the same data.

In Processor Mode, the microprocessor writes data to the connection memory locations corresponding to the stream and channel that is to be output. The lower half (8 least significant bits) of the connection memory is output every frame until the microprocessor changes the data or mode of the channel. By using this Processor Mode capability, the microprocessor can access input and output time-slots on a per channel basis.

The four most significant bits of the connection memory are used to control per channel functions of the out put streams. Specifically, there are bits for Processor or Connection mode, Constant or Variable delay, enables or disables of output drivers, and controls for the Loopback function.

If the per channel OE is set to zero, only that particular channel (8-bits) will be in the high-impedance state. If however, the ODE input pin is low or the Output Standby Bit (OSB) in the Control Register is low, all of the outputs will be in a high-impedance state even if a particular channel in connection memory has enabled the output for that channel. In other words, the ODE pin and OSB control bit are master output enables for the device (Table 3).

#### **SERIAL DATA INTERFACE TIMING**

The master clock frequency must always be twice the data rate. For a serial data rates of 2.048 Mb/s, the master clock (CLK) must be at 4.096 MHz. The input and output stream data rates will always be identical.

The IDT72V70210 provides two different interface timing modes, ST-BUS  $^{\circ}$  or GCI. The IDT72V70210 automatically detects the presence of an input frame pulse and identifies it as either ST-BUS  $^{\circ}$  or GCI. In ST-BUS  $^{\circ}$  format, every second falling edge of the master clock marks a bit boundary and the data is clocked in on the rising edge of CLK, three quarters of the way into the bit cell. In GCI format, every second rising edge of the master clock marks the bit boundary and data is clocked in on the falling edge of CLK at three quarters of the way into the bit cell.

#### INPUT FRAME OFFSET SELECTION

Input frame offset selection allows the channel alignment of individual input streams to be offset with respect to the output stream channel alignment (i.e.  $\overline{F0i}$ ). Although all input data comes in at the same speed, delays can be caused by variable path serial backplanes and variable path lengths which may be implemented in large centralized and distributed switching systems. Because data is often delayed this feature is useful in compensating for the skew between clocks.

Each input stream can have its own delay offset value by programming the frame input offset registers (FOR, Table 8). The maximum allowable skew is +4 master clock (CLK) periods forward with a resolution of 1/2 clock period. The output frame offset cannot be offset or adjusted.

#### SERIAL INPUT FRAME ALIGNMENT EVALUATION

The IDT72V70210 provides the frame evaluation (FE) input to determine different data input delays with respect to the frame pulse  $\overline{\text{FOi}}$ .

Ameasurement cycle is started by setting the start frame evaluation (SFE) bit lowfor at least one frame. When the SFE bit in the Control Register is changed from low to high, the evaluation starts. Two frames later, the complete frame evaluation (CFE) bit of the frame alignment register (FAR) changes from low to high to signal that a valid offset measurement is ready to be read from bits 0 to 11 of the FAR register. The SFE bit must be set to zero before a new measurement cycle is started.

In ST-BUS mode, the falling edge of the frame measurement signal (FE) is evaluated against the falling edge of the ST-BUS frame pulse. In GCI mode, the rising edge of FE is evaluated against the rising edge of the GCI frame pulse. See Table 7 and Figure 1 for the description of the frame alignment register.

#### MEMORY BLOCK PROGRAMMING

The IDT72V70210 provides users with the capability of initializing the entire connection memory block in two frames. To set bits 12 to 15 of every connection memory location, first program the desired pattern in bits 5 to 8 of the Control Register.

The block programming mode is enabled by setting the memory block program (MBP) bit of the control register high. When the block programming enable (BPE) bit of the Control Register is set to high, the block programming data will be loaded into the bits 12 to 15 of every connection memory location. The other connection memory bits (bit 0 to bit 11) are loaded with zeros. When the memory block programming is complete, the device resets the BPE bit to zero.

#### LOOPBACK CONTROL

The loopback control (LPBK) bit of each connection memory location allows the TX output data to be looped backed internally to the RX input for diagnostic purposes.

If the LPBK bit is high, the associated TX output channel data is internally looped back to the RX input channel (i.e., data from TXn channel m routes to the RXn channel m internally); if the LPBK bit is low, the loopback feature is

disabled. For proper per-channel loopback operation, the contents of frame delay offset registers must be set to zero.

## **DELAY THROUGH THE IDT72V70210**

The switching of information from the input serial streams to the output serial streams results in a throughput delay. The device can be programmed to perform time-slot interchange functions with different throughput delay capabilities on a per-channel basis. For voice applications, variable throughput delay is best as it ensure minimum delay between input and output data. In wideband data applications, constant throughput delay is best as the frame integrity of the information is maintained through the switch.

The delay through the device varies according to the type of throughput delay selected in the  $\overline{V}/C$  bit of the connection memory.

## VARIABLE DELAY MODE ( $\overline{V}/C$ BIT = 0)

In this mode, the delay is dependent only on the combination of source and destination channels and is independent of input and output streams. The minimum delay achievable in the IDT72V70210 is three time-slots. If the input channel data is switched to the same output channel (channel n, frame p), it will be output in the following frame (channel n, frame p+1). The same is true if the input channel n is switched to output channel n+1 or n+2. If the input channel n is switched to output channel n+3, n+4,..., the new output data will appear in the same frame. Table 2 shows the possible delays for the IDT72V70210 in the variable delay mode.

## CONSTANT DELAY MODE ( $\overline{V}/C$ BIT = 1)

In this mode, frame integrity is maintained in all switching configurations by making use of a multiple data memory buffer. Input channel data is written into the data memory buffers during frame n will be read out during frame n+2. In the IDT72V70210, the minimum throughput delay achievable in the constant delay mode will be one frame. For example, when input time-slot 31 is switched to output time-slot 0. The maximum delay of 94 time-slots of delay occurs when time-slot 0 in a frame is switched to time-slot 31 in the frame.

## **MICROPROCESSOR INTERFACE**

The IDT72V70210's microprocessor interface looks like a standard RAM interface to improve integration into a system. With a 12-bit address bus and a 16-bit data bus, read and writes are mapped directly into Data and Connection memories and require only one cycle to access. By allowing the internal memories to be randomly accessed in one cycle, the controlling microprocessor has more time to manage other peripheral devices and can more easily and quickly gather information and setup the switch paths.

Table 4 shows the mapping of the addresses into internal memory blocks and Table 5 shows the Control Register information.

### **MEMORY MAPPING**

The address bus on the microprocessor interface selects the internal registers and memories of the IDT72V70210.

The two most significant bits of the address select between the registers, Data Memory, and Connection Memory. If A11 and A10 are HIGH, A9-A0 are used to address the Data Memory. If A11 is HIGH and A10 is LOW, A9-A0 are used to address Connection Memory. If A11 is LOW and A10 is HIGH A9-A0 are used to select the Control Register, Frame Alignment Register, and Frame Offset Registers. See Table 4 for mappings.

As explained in the Serial Data Interface Timing and Switching Configurations sections, after system power-up, the Control Register should be programmed immediately to establish the desired switching configuration.

The data in the Control Register consists of the Memory Block Programming bit (MBP), the Block Programming Data (BPE) bits, the Begin Block Programming Enable (BPE), the Output Stand By, Start Frame Evaluation, and Data Rate Select bits. As explained in the Memory Block Programming section, the BPE begins the programming if the MBP bit is enabled. This allows the entire connection memory block to be programmed with the Block Programming Data bits. If the ODE pin is low, the OSB bit enables (if high) or disables (if low) all TX output drivers. If the ODE pin is high, the contents of the OSB bit is ignored and all TX output drivers are enabled.

#### CONNECTION MEMORY CONTROL

If the ODE pin or the OSB bit is high, the OE bit of each connection memory location controls the output drivers-enables (if high) or disables (if low). See Table 3 for detail.

The Processor Channel (PC) bit of the Connection Memory selects between Processor Mode and Connection Mode. If high, the contents of the Connection Memory are output on the TX streams. If low, the Stream Address Bit (SAB) and the Channel Address Bit (CAB) of the Connection Memory defines the source information (stream and channel) of the time-slot that will be switched to the output from Data Memory.

Also in the Connection Memory is the  $\overline{V}/C$  (Variable/Constant Delay) bit. Each Connection Memory location allows the per-channel selection between variable and constant throughput delay modes.

If the LPBK bit is high, the associated TX output channel data is internally looped back to the RX input channel (i.e., RXn channel m data comes from the TXn channel m). If the LPBK bit is low, the loopback feature is disabled. For proper per-channel loopback operation, the contents of the frame delay offset registers must be set to zero.

## **INITIALIZATION OF THE IDT72V70210**

After power up, the state of the connection memory is unknown. As such, the outputs should be put in high impedance by holding the ODE low. While the ODE is low, the microprocessor can initialize the device, program the active paths, and disable unused outputs by programming the OE bit in connection memory. Once the device is configured, the ODE pin (or OSB bit depending on initialization) can be switched.

## TABLE 1 — CONSTANT THROUGHPUT DELAY VALUE

Input Rate	Delay for Constant Throughput Delay Mode (m – output channel number) (n – input channel number)
2.048 Mb/s	32 + (32 – n) +m time-slots

## TABLE 2 — VARIABLE THROUGHPUT DELAY VALUE

Input Rate	Delay for Variable Throughput Delay Mode (m – output channel number; n – input channel number)									
	m < n	m = n, n+1, n+2	m > n+2							
2.048 Mb/s	32 – (n-m) time-slots	(m-n + 32) time slots	(m-n) time-slots							

## **TABLE 3 — OUTPUT HIGH IMPEDANCE CONTROL**

OE bit in Connection Memory	ODE pin	OSB bit in CR Register	TX Stream Output Status
0	Don't Care	Don't Care	Per Channel High-Impedance
1	0	0	High-Impedance
1	0	1	Enable
1	1	0	Enable
1	1	1	Enable

## **TABLE 4 — INTERNAL REGISTER AND ADDRESS MEMORY MAPPING**

A11	A10	A9	A8	A7	A6	<b>A</b> 5	A4	A3	A2	A1	A0	RW	Location
1	1	STA4	STA3	STA2	STA1	STA0	CH4	CH3	CH2	CH1	CH0	R	Data Memory
1	0	STA4	STA3	STA2	STA1	STA0	CH4	CH3	CH2	CH1	CH0	R/W	Connect. Memory
0	1	0	0	0	0	Х	Х	Х	Х	Х	Х	R/W	Control Register
0	1	0	0	0	1	Х	Х	Х	Х	Х	Х	R/W	Frame Align Register
0	1	0	0	1	0	Х	Х	Х	Х	Х	Х	R/W	FOR0
0	1	0	0	1	1	Х	Х	Х	Х	Х	Х	R/W	FOR1
0	1	0	1	0	0	Х	Х	Х	Х	Х	Х	R/W	FOR2
0	1	0	1	0	1	Х	Х	Х	Х	Х	Х	R/W	FOR3
0	1	0	1	1	0	Х	Х	Х	Х	Х	Х	R/W	FOR4
0	1	0	1	1	1	Х	Х	Х	Х	Х	Х	R/W	FOR5
0	1	1	0	0	0	Х	Х	Х	Х	Х	Х	R/W	FOR6
0	1	1	0	0	1	Х	Х	Х	Х	Х	Х	R/W	FOR7

## TABLE 5 — CONTROL REGISTER (CR) BITS

Rese	Reset Value:		000	0н.													
	15	5 14	13	12	11	10	9	8	7	6	5	4	3	2	1	0	
	0	0	0	0	0	0	МВР	BPD3	BPD2	BPD1	BPD0	ВРЕ	OSB	SFE	0	0	
Bit		Name			Description	)											
15-10		Unused			Must be zero	for norr	malopera	tion.									
9		MBP (Memory Blo	ock Progra	ım)		When 1, the connection memory block programming feature is ready for the programming of Connection Memory high bits, bit 11 to bit 15. When 0, this feature is disabled.											
8-5	BPD4-0 (Block Programming Data)				These bits carry the value to be loaded into the connection memory block whenever the memory block programming feature is activated. After the MBP bit in the control register is set to 1 and the BPE bit is set to 1, the contents of the bits BPD3-0 are loaded into bit 15 and 12 of the connection memory. Bit 11 to bit 0 of the connection memory are set to 0.												
4	BPE (Begin Block Programming Enable)				A zero to one register hav complete the operation is BPE = 1, the	e to be o e block p comple	lefined in rogramm ted. Whe	the same ing. Aftert n the BPE	write ope he progra = 1, the I	ration. On mming fur 3PE or Mi	ice the BP nction has BP can be	E bit is se finished, set to 0 t	et HIGH, t the BPE b o abort to	he device oit returns ensure p	e require to zero t roper op	s two frame o indicate th	es to ne
3	OSB (Output Stand By)				When ODE = 0 and OSB = 0, the output drivers of TX0 to TX31 are in high impedance mode. When ODE = 0 and OSB = 1, the output driver of TX0 to TX31 function normally. When ODE = 1, TX0 to TX31 output drivers function normally.												
2	SFE (Start Frame Evaluation)			n)	A zero to one transition in this bit starts the frame evaluation procedure. When the CFE bit in the FAR register changes from zero to one, the evaluation procedure stops. To start another fame evaluation cycle, set this bit to zero for at least one frame.												
1-0		Unused			Must be zero	fornorr	malopera	tion.									

## **TABLE 6 — CONNECTION MEMORY BITS**

15	14 13 12	11 10 9 8 7 6 5 4 3 2 1 0
LPB	K V/C PC OE	SAB4 SAB3 SAB2 SAB1 SAB0 0 0 CAB4 CAB3 CAB2 CAB1 CAB0
Bit	Name	Description
15	LPBK (Per Channel Loopback)	When 1, the RX n channel  m  data  comes  from  the  TX  n  channel  m.  For  proper  per  channel  loopback  operations,  set  the  delay  offset  register  bits  OFn [2:0]  to  zero  for  the  streams  which  are  in  the  loopback  mode.
14	√/C (Variable/Constant Throughput Delay)	This bit is used to select between the variable (LOW) and constant delay (HIGH) mode on a per-channel basis.
13	P C (Processor Channel)	When 1, the contents of the connection memory are output on the corresponding output channel and stream. Only the lower byte (bit 7 – bit 0) will be output to the TX output pins. When 0, the contents of the connection memory are the data memory address of the switched input channel and stream.
12	O E (Output Enable)	This bit enables the TX output drivers on a per-channel basis. When 1, the output driver functions normally. When 0, the output driver is in a high-impedance state.
11-7	SAB4-0 (Source Stream Address Bits)	The binary value is the number of the data stream for the source of the connection.
6-5	Unused	Must be zero for normal operation.
4-0	CAB4-0 (Source Channel Address Bits)	The binary value is the number of the channel for the source of the connection.

## **TABLE 7 — FRAME ALIGNMENT REGISTER (FAR) BITS**

Reset	/alue: 00	000н.
	15 14	13 12 11 10 9 8 7 6 5 4 3 2 1 0
	0 0	0 CFE FD11 FD10 FD9 FD8 FD7 FD6 FD5 FD4 FD3 FD2 FD1 FD0
Bit	Name	Description
15-13	Unused	Must be zero for normal operation
12	CFE (Complete Frame Evaluation)	When CFE = 1, the frame evaluation is completed and bits FD10 to FD0 bits contains a valid frame alignment offset. This bit is reset to zero, when SFE bit in the CR register is changed from 1 to 0.
11	FD11 (Frame Delay Bit 11)	The falling edge of FE (or rising edge for GCI mode) is sampled during the CLK-high phase (FD11 = 1) or during the CLK-low phase (FD11 = 0). This bit allows the measurement resolution to ½ CLK cycle.
10-0	FD10-0 (Frame Delay Bits)	The binary value expressed in these bits refers to the measured input offset value. These bits are rest to zero when the SFE bit of the CR register changes from 1 to 0. (FD10 – MSB, FD0 – LSB)

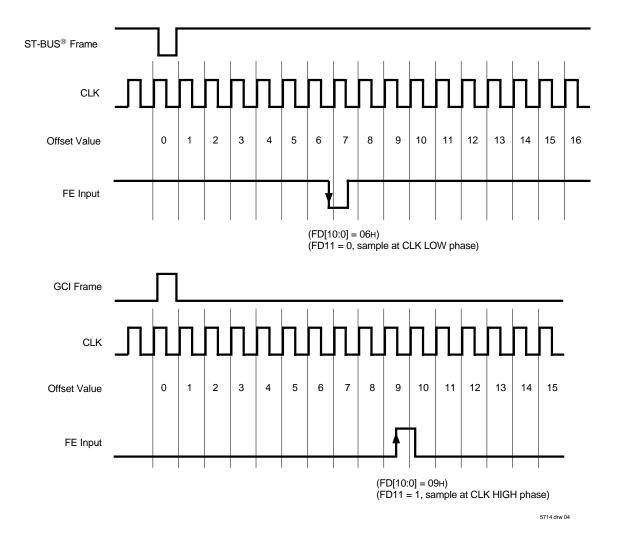


Figure 1. Example for Frame Alignment Measurement

## TABLE 8 — FRAME INPUT OFFSET REGISTER (FOR) BITS

Re	eset Value	<u>)</u> :	0000⊦	for all FO	Rregister	S.										
15 OF32	14 OF31	13 OF30	12 DLE3	11 OF22	10 OF21	9 OF20	8 DLE2	7 OF12	6 OF11	5 OF10	4 DLE1	3 OF02	2 OF01	1 OF00	0 DLE0	]
3.32	0.0.		J _ 5226	0,22	9.2.	0.20				9	DEE.	0.02			5220	]
15	14	13	12	11	10	9	8 8	FOR0 Reg	gister 6	5	4	3	2	1	0	
OF72	OF71	OF70	DLE7	OF62	OF61	OF60	DLE6	OF52	OF51	OF50	DLE5	OF42	OF41	OF40	DLE4	
							F	OR1 Re	gister							•
15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0	1
OF112	OF111	OF110	DLE11	OF102	OF101	OF100	DLE10	OF92	OF91	OF90	DLE9	OF82	OF81	OF80	DLE8	
							ı	OR2 Re	gister							•
15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0	1
OF312	OF311	OF310	DLE31	OF142	OF141	OF140	DLE14	OF132	OF131	OF130	DLE13	OF122	OF121	OF120	DLE12	
15	14	13	12	11	10	9	<b>8</b>	FOR3 Reg	gister 6	5	4	3	2	1	0	
OF192	OF191	OF190	DLE19	OF182	OF181	OF180	DLE18	OF172	OF171	OF170	DLE17	OD162	OD161	OF160	DLE16	
							F	OR4 Reg	gister							
15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0	1
OF232	OF231	OF230	DLE23	OF222	OF221	OF220	DLE22	OF212	OF211	OF210	DLE21	OF202	OF201	OF200	DLE20	
								FOR5 Reg		_						
15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0	1
OF272	OF271	OF270	DLE27	OF262	OF261	OF260	DLE26	OF252	OF251	OF250	DLE25	OF242	OF241	OF240	DLE24	
								FOR6 Req	•							
15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0	1
OF312	OF311	OF310	DLE31	OF302	OF301	OF300	DLE30	OF292	OF291	OF290	DLE29	OF282	OF281	OF280	DLE28	
							F	FOR7 Req	gister							
Nar	me <sup>(1)</sup>		Descripti	on												
	OFn2, OFn1, OFn0 (Offset Bits 2, 1 & 0) These three bits define how long the serial interface receiver takes to recognize and store bit 0 from the RX input pin: i.e., to start a new fram The input frame offset can be selected to +4.5 clock periods from the point where the external frame pulse input signal is applied to the F0i input of the device. See Figure 1.															
DLEn			ST-BUS (Data La	* mode: tch Edge)	DL DL	En = 0, if En = 1, if	when clo	ck falling	edge is at	point of the	ne bit cell	l.				
			GCI mod	ae:						point of the the ¾ of th						

NOTE:

1. n denotes an input stream number from 0 to 31.

## TABLE 9 — OFFSET BITS (OFn2, OFn1, OFn0, DLEn) & FRAME DELAY BITS (FD11, FD2-0)

Input Stream			nt Result from Delay Bits		Corresponding Offset Bits					
Offset	FD11	FD2	FD1	FD0	OFn2	OFn1	OFn0	DLEn		
No clock period shift (Default)	1	0	0	0	0	0	0	0		
+ 0.5 clock period shift	0	0	0	0	0	0	0	1		
+ 1.0 clock period shift	1	0	0	1	0	0	1	0		
+ 1.5 clock period shift	0	0	0	1	0	0	1	1		
+ 2.0 clock period shift	1	0	1	0	0	1	0	0		
+ 2.5 clock period shift	0	0	1	0	0	1	0	1		
+ 3.0 clock period shift	1	0	1	1	0	1	1	0		
+ 3.5 clock period shift	0	0	1	1	0	1	1	1		
+ 4.0 clock period shift	1	1	0	0	1	0	0	0		
+ 4.5 clock period shift	0	1	0	0	1	0	0	1		

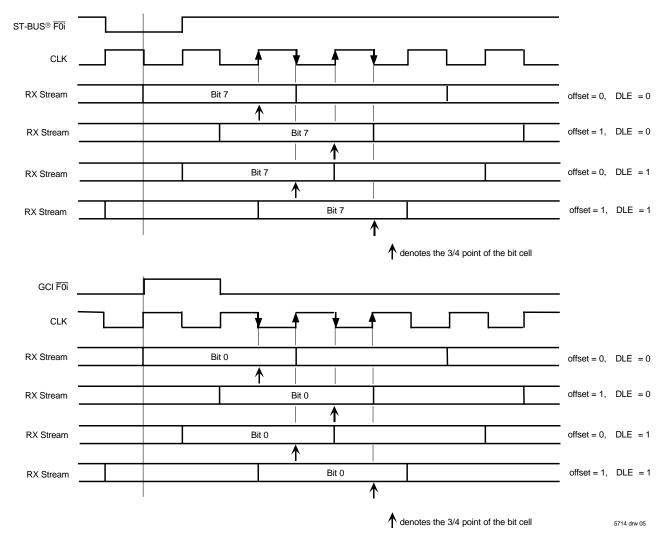


Figure 2. Examples for Input Offset Delay Timing

## JTAG SUPPORT

The IDT72V70210 JTAG interface conforms to the Boundary-Scan standard IEEE-1149.1. This standard specifies a design-for-testability technique called Boundary-Scan test (BST). The operation of the boundary-scan circuitry is controlled by an external test access port (TAP) Controller.

### **TEST ACCESS PORT (TAP)**

The Test Access Port (TAP) provides access to the test functions of the IDT72V70210. It consists of three input pins and one output pin.

Test Clock Input (TCK)

TCK provides the clock for the test logic. The TCK does not interfere with any on-chip clock and thus remain independent. The TCK permits shifting of test data into or out of the Boundary-Scan register cells concurrently with the operation of the device and without interfering with the on-chip logic.

Test Mode Select Input (TMS)

The logic signals received at the TMS input are interpreted by the TAP Controller to control the test operations. The TMS signals are sampled at the rising edge of the TCK pulse. This pin is internally pulled to Vcc when it is not driven from an external source.

Test Data Input (TDI)

Serial input data applied to this port is fed either into the instruction register or into a test data register, depending on the sequence previously applied to the TMS input. Both registers are described in a subsequent section. The received input data is sampled at the rising edge of TCK pulses. This pin is internally pulled to Vcc when it is not driven from an external source.

Test Data Output (TDO)

Depending on the sequence previously applied to the TMS input, the contents of either the instruction register or data register are serially shifted out

towards the TDO. The data out of the TDO is clocked on the falling edge of the TCK pulses. When no data is shifted through the boundary scan cells, the TDO driver is set to a high impedance state.

•Test Reset (TRST)

Reset the JTAG scan structure. This pin is internally pulled to Vcc.

#### **INSTRUCTION REGISTER**

In accordance with the IEEE-1149.1 standard, the IDT72V70210 uses public instructions. The IDT72V70210 JTAG Interface contains a two-bit instruction register. Instructions are serially loaded into the instruction register from the TDI when the TAP Controller is in its shifted-IR state. Subsequently, the instructions are decoded to achieve two basic functions: to select the test data register that may operate while the instruction is current, and to define the serial test data register path, which is used to shift data between TDI and TDO during data register scanning.

#### **TEST DATA REGISTER**

As specified in IEEE-1149.1, the IDT72V70210 JTAG Interface contains two test data registers:

•The Boundary-Scan register

The Boundary-Scan register consists of a series of Boundary-Scan cells arranged to form a scan path around the boundary of the IDT72V70210 core logic.

The Bypass Register

The Bypass register is a single stage shift register that provides a one-bit path from TDI to its TDO. The IDT72V70210 boundary scan register bits are shown in Table 10. Bit 0 is the first bit clocked out. All three-state enable bits are active high.

## **TABLE 10 — BOUNDARY SCAN REGISTER BITS**

	Boundary Scan Bit 0 to bit 167							
Device Pin	Three-State	Output	Input					
Device I III	Control	Scan Cell	Scan Cell					
ODE			0					
RESET			1					
CLK			2					
F0i			3					
FE			4					
IC			5					
DS			6					
CS			7					
R/W			8					
A0			9					
A1			10					
A2			11					
A3			12					
A4			13					
IC			14					
IC			15					
<b>A</b> 5			16					
A6			17					
A7			18					
A8			19					
A9			20					
A10			21					
A11			22					
DTA		23						
D15	24	25	26					
D14	27	28	29					
D13	30	31	32					
D12	33	34	35					
D11	36	37	38					
D10	39	40	41					
D9	42	43	44					
D8	45	46	47					
D7	48	49	50					
D6	51	52	53					
D5	54	55	56					
D4	57	58	59					
D3	60	61	62					
D2	63	64	65					
D1	66	67	68					
D0	69	70	71					
TX31	72	73						
TX30	74 74	75 77						
TX29	76 78	77 79						
TX28 TX27	78 80	81						
TX27	80 82	83						
TX25	82 84	83 85						
TX25	86	87						
RX31	00	U/	88					
RX30			89					
RX29			90					
RX29 RX28			90 91					
ΓΛΖΟ		l	71					

	Boundary Scan Bit 0 to bit 167				
Device Pin	Three-State	Output	Input		
	Control	Scan Cell	Scan Cell		
RX27			92		
RX26			93		
RX25			94		
RX24			95		
TX23	96	97			
TX22	98	99			
TX21	100	101			
TX20	102	103			
TX19	104	105			
TX18	106	107			
TX17	108	109			
TX16	110	111	440		
RX23			112		
RX22			113		
RX21			114		
RX20			115		
RX19			116		
RX18 RX17			117		
			118		
RX16 TX15	120	121	119		
TX15	120	121			
TX13	124	125			
TX13	124	125			
TX12	128	127			
TX10	130	131			
TX9	132	133			
TX8	134	135			
RX15	154	100	136		
RX14			137		
RX13			138		
RX12			139		
RX11			140		
RX10			141		
RX9			142		
RX8			143		
TX7	144	145			
TX6	146	147			
TX5	148	149			
TX4	150	151			
TX3	152	153			
TX2	154	155			
TX1	156	157			
TX0	158	159			
RX7			160		
RX6			161		
RX5			162		
RX4			163		
RX3			164		
RX2			165		
RX1			166		
RX0			167		

## **ABSOLUTE MAXIMUM RATINGS(1)**

Symbol	Parameter	Min.	Max.	Unit
Vcc	Supply Voltage	3.0	3.6	٧
Vi	Voltage on Digital Inputs	GND -0.3	5.3	٧
lo	Current at Digital Outputs	-50	50	mA
Ts	Storage Temperature	-55	+125	°C
PD	Package Power Dissapation	_	2	W

#### NOTE:

## RECOMMENDED OPERATING CONDITIONS<sup>(1)</sup>

Symbol	Parameter	Min.	Тур.	Max.	Unit
Vcc	Positive Supply	3.0	3.3	3.6	V
VIH	Input HIGH Voltage	2.0		5.3	V
VIL	Input LOW Voltage	_	_	0.8	V
Тор	Operating Temperature Commercial	-40	25	+85	°C

#### NOTE:

1. Voltages are with respect to Ground unless otherwise stated.

## DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Min.	Тур.	Max.	Units
Icc (2)	Supply Current @ 2 Mb/s	-	15	20	mA
IIL <sup>(3,4)</sup>	Input Leakage (input pins)	-	-	50	μΑ
loz <sup>(3,4)</sup>	High-impedance Leakage	-	-	50	μΑ
VoH <sup>(5)</sup>	Output HIGH Voltage	2.4	-	-	V
Vol <sup>(6)</sup>	Output LOW Voltage	-	-	0.4	V

#### NOTES:

- 1. Voltages are with respect to ground (GND) unless otherwise stated.
- 2. Outputs unloaded.
- 3.  $0 \le V \le VCC$ .
- 4. Maximum leakage on pins (output or I/O pins in high-impedance state) is over an applied voltage (V).
- 5. IOH = 10 mA.
- 6. IOL = 10 mA.

## AC ELECTRICAL CHARACTERISTICS - TIMING PARAMETER MEASUREMENT VOLTAGE LEVELS

Symbol	Rating	Level	Unit
VTT	TTLThreshold	1.5	٧
VHM	TTL Rise/Fall Threshold Voltage HIGH	2.0	٧
VLM	TTL Rise/Fall Threshold Voltage LOW	8.0	V

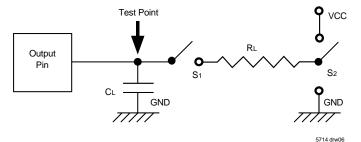


Figure 3. Output Load

S1 is open circuit except when testing output levels or high impedance states.

S2 is switched to VCC or GND when testing output levels or high impedance states.

<sup>1.</sup> Exceeding these values may cause permanent damage. Functional operation under these conditions is not implied.

## **AC ELECTRICAL CHARACTERISTICS - FRAME PULSE AND CLK**

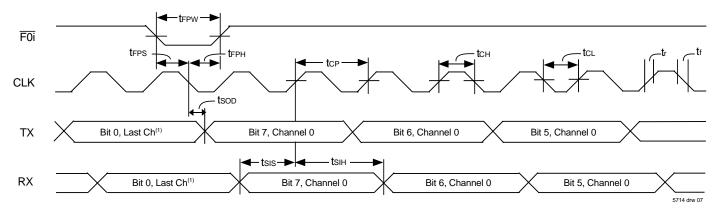
Symbol	Parameter	Min.	Тур.	Max.	Units
tfpw	Frame Pulse Width (ST-BUS®, GCI) Bit rate = 2.048 Mb/s	26	_	295	ns
tfps	Frame Pulse Setup time before CLK falling (ST-BUS® or GCI)	10	_		ns
tfph	Frame Pulse Hold Time from CLK falling (ST-BUS® or GCI)	16	_		ns
tcp	CLK Period Bit rate = 2.048 Mb/s	190	_	300	ns
tсн	CLK Pulse Width HIGH Bit rate = 2.048 Mb/s	85	_	150	ns
tcl	CLK Pulse Width LOW Bit rate = 2.048 Mb/s	85	_	150	ns
tr, tf	Clock Rise/Fall Time	_	_	10	ns

## AC ELECTRICAL CHARACTERISTICS(1) — SERIAL STREAM (ST-BUS® and GCI)

Symbol	Parameter	Min.	Тур.	Max.	Units
tsis	RX Setup Time	5	_	_	ns
tsih	RX Hold Time	10		_	ns
tsod	TX Delay – Active to Active				
	@ 2.048 Mb/s	_	_	30	ns
tDZ	TX Delay – Active to High-Z				
	@ 2.048 Mb/s	_	_	30	ns
tzd	TX Delay – High-Z to Active				
	@ 2.048 Mb/s	_	_	30	ns
tode	Output Driver Enable (ODE) Delay				
	@ 2.048 Mb/s		_	30	ns

### NOTE:

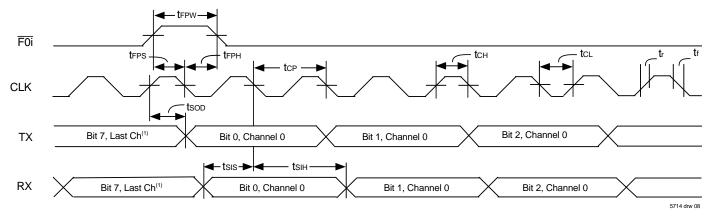
<sup>1.</sup> High Impedance is measured by pulling to the appropriate rail with  $R_L$  (1K), with timing corrected to cancel time taken to discharge  $C_L$  (150 pF).



#### NOTE:

1. @ 2.048 Mb/s bit rate, last channel = ch 31,

Figure 4. ST-BUS® Timing



### NOTE:

1. @ 2.048 Mb/s, last channel = ch 31,

Figure 5. GCI Timing

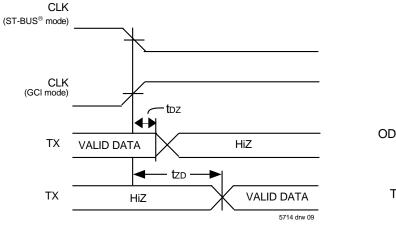


Figure 6. Serial Output and External Control

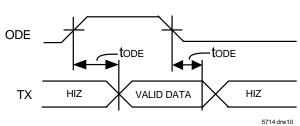


Figure 7. Output Driver Enable (ODE)

## **AC ELECTRICAL CHARACTERISTICS - MICROPROCESSOR INTERFACE TIMING**

Symbol	Parameter	Min.	Тур.	Max.	Units
tcss	CS Setup from DS falling	0			ns
trws	R/W Setup from DS falling	3			ns
tads	Address Setup from DS falling	2			ns
tсsн	CS Hold after DS rising	0			ns
trwн	R/W Hold after DS Rising	3			ns
tadh	Address Hold after DS Rising	2		_	ns
t <sub>DDR</sub> (1)	Data Setup from DTA LOW on Read	2			ns
t <sub>DHR</sub> (1,2,3)	Data Hold on Read	10	15	25	ns
tosw	Data Setup on Write (Fast Write)	10			ns
tswd	Valid Data Delay on Write (Slow Write)	-		0	ns
tohw	Data Hold on Write	5		_	ns
takd <sup>(1)</sup>	Acknowledgment Delay: Reading/Writing Registers Reading/Writing Memory			30 345	ns ns
takh <sup>(1,2,3)</sup>	Acknowledgment Hold Time	_	_	20	ns
toss (4)	Data Strobe Setup Time	2	_	_	ns

### NOTES:

- 1. CL= 150pF
- 2. RL = 1K
- 3. High Impedance is measured by pulling to the appropriate rail with R<sub>L</sub>, with timing corrected to cancel time taken to discharge C<sub>1</sub>.
- 4. To achieve one clock cycle fast memory access, this setup time, toss should be met. Otherwise, memory access operation is determined by take, which in worst case is 345 ns.

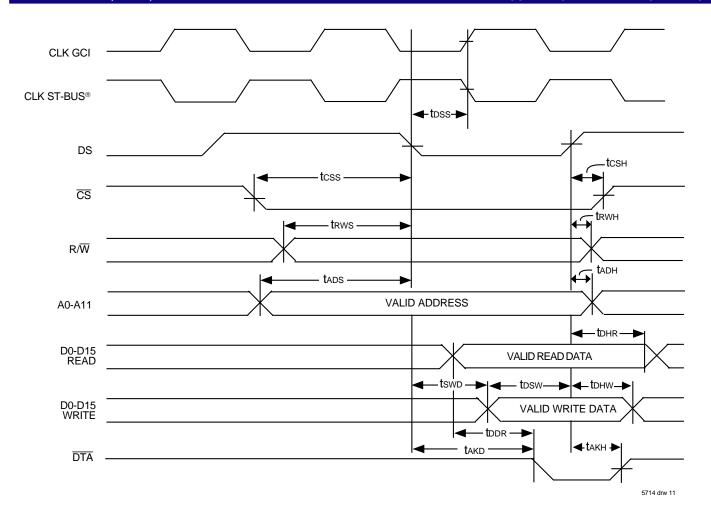
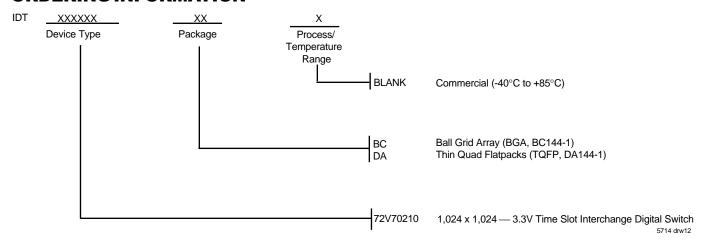


Figure 8. Motorola Non-Mulitplexed Bus Timing

## **ORDERING INFORMATION**



## **DATASHEET DOCUMENT HISTORY**

5/05/2000 pg. 1

6/08/2000 pgs. 1, 2, 3 and 18.

8/30/2000 pgs. 2, 4, 5, 7, 9, 13 and 17.

01/24/2001 pg. 13 10/22/2001 pg. 1 1/04/2002 pgs. 1 and 14.



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